ASSP BIPOLAR

VOLTAGE DETECTOR

MB3761

DESCRIPTION

Designed for voltage detector applications, the Fujitsu MB3761 is a dual comparator with a built-in high precision reference voltage generator. Outputs are open-collector outputs and enable use of the OR-connection between both channels. Both channels have hysteresis control outputs. Because of a wide power supply voltage range and a low power supply current, the MB3761 is suitable for power supply monitors and battery backup systems.

■ FEATURES

- Wide power supply voltage range: 2.5 V to 40 V
- Low power and small voltage dependency supply current: 250 μA Typ
- Built-in stable low voltage generator: 1.20 V Typ
- Easy-to-add hysteresis characteristics.
- One type of package (SOP-8pin : 1 type)

APPLICATIONS

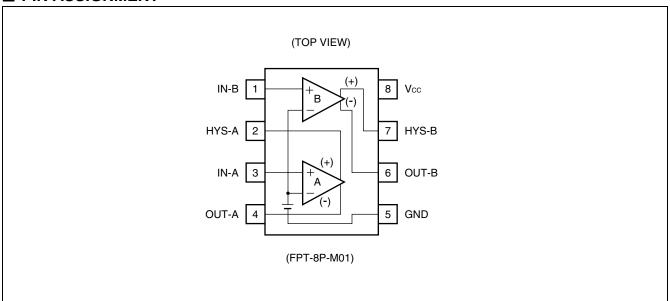
- Industrial Equipment
- Arcade Amusement etc.



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■ PIN ASSIGNMENT



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rat	Unit		
Farameter	Зушьог	Min	Max	Oille	
Power Supply Voltage	Vcc	_	41	V	
Output Voltage	Vo	_	41	V	
Output Current	lo	_	50	mA	
Input Voltage	Vin	- 0.3	+ 6.5	V	
Power Dissipation	Pb	_	350 (T _A ≤ +70°C)	mW	
Storage Temperature	Tstg	- 55	+ 125	°C	

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value		Unit
		Min	Max	Onit
Power Supply Voltage	Vcc	2.5	40	V
Operating Ambient Temperature	TA	- 20	+ 75	°C
Output Current at pin 4	lO4	_	4.5	mA
Output Current at pin 6	IO6	_	3.0	mA

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

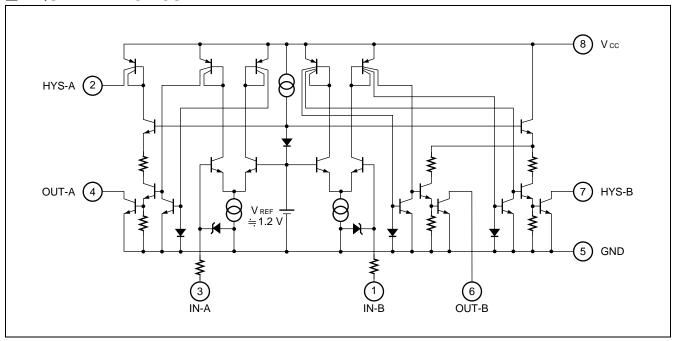
No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

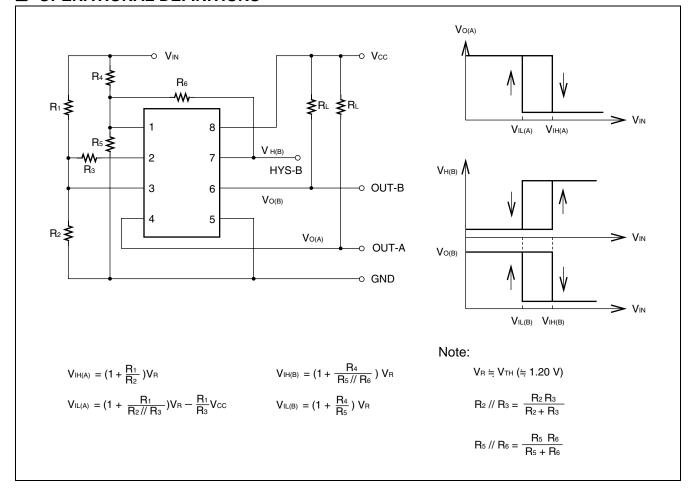
(TA=+25°C, VCC=5 V)

Parameter	0	Conditions	Value			
	Symbol	Conditions	Min	Тур	Max	Unit
Power Supply Voltage	ICCL	VCC= 40 V, VIL= 1.0 V	-	250	400	μΑ
	Іссн	VCC= 40 V, VIH= 1.5 V	-	400	600	μΑ
Threshold Voltage	VTH	Io = 2 mA, Vo= 1 V	1.15	1.20	1.25	V
Deviation of Threshold Voltage	Δ VTH1	2.5 V ≤ VCC ≤ 5.5 V	-	3	12	mV
	Δ VTH2	4.5 V ≤ VCC ≤ 40 V	-	10	40	mV
Offset Voltage between Outputs	Voosa	IOA= 4.5 mA, VOA= 2 V, IHA= 20 μA, VHA= 3 V	-	2.0	-	mV
	Vossb	IOB= 3 mA, VOB= 2 V, IHB= 3 mA, VHB= 2 V	-	2.0	-	mV
Temperature Coefficient of Threshold Voltage	α	-20°C ≤ TA ≤ +70°C	-	±0.05	-	mV/°C
Difference Voltage on Threshold Voltage between Channel	Δ VTHAB	-	-10	-	+10	mV
1	lı∟	VIL= 1.0 V	-	5		nA
Input Current	lін	VIH= 1.5 V	-	100	500	nA
Output Leakage Current	Іон	Vo= 40 V, VIL= 1.0 V	-	-	1	μΑ
Hysteresis Output Leakage Current	IHLA	VCC= 40 V, VHA= 0 V, VIL= 1.0 V	-	-	0.1	μΑ
	Іннв	VHB= 40 V, VIH= 1.5 V	-	-	1	μΑ
Output Sink Current	IOLA	Vo= 1.0 V, VIH= 1.5 V	6	12	-	mA
Output Sink Current	IOLB	Vo= 1.0 V, VIH= 1.5 V	4	10	-	mA
Hysteresis Current	Інна	VH= 0 V, VIH= 1.5 V	40	80	-	μΑ
	IHLB	VH= 1.0 V,VIL = 1.0 V	4	10	-	mA
Output Saturation Voltage	Vola	IO= 4.5 mA, VIH= 1.5 V	-	120	400	mV
	Volb	IO= 3.0 mA, VIH= 1.5 V	-	120	400	mV
Hysteresis Saturation	VHHA	IH= 20 μA, VIH= 1.5 V	-	50	200	mV
	VHLB	IH= 3.0 mA, VIL= 1.0 V	-	120	400	mV
Output Delay Time	tPHL	$RL=5 k\Omega$	-	2	-	μs
	tPLH	$RL=5 k\Omega$	-	3	-	μs

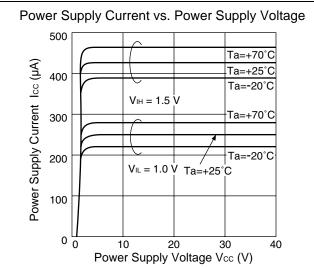
■ EQUIVALENT CIRCUIT



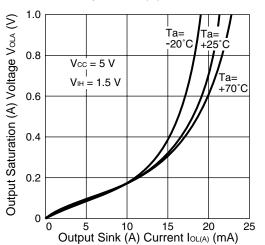
■ OPERATIONAL DEFINITIONS



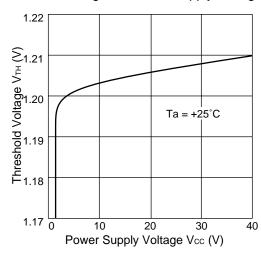
■ TYPICAL PERFORMANCE CHARACTERISTICS

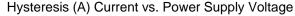


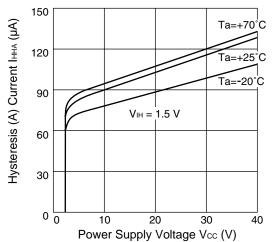
Output Saturation (A) Voltage vs.
Output Sink (A) Current



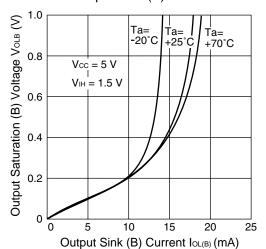
Threshold Voltage vs. Power Supply Voltage



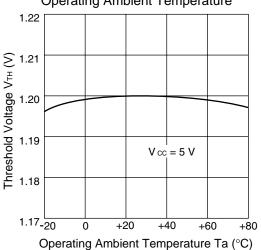




Output Saturation (B) Voltage vs.
Output Sink (B) Current

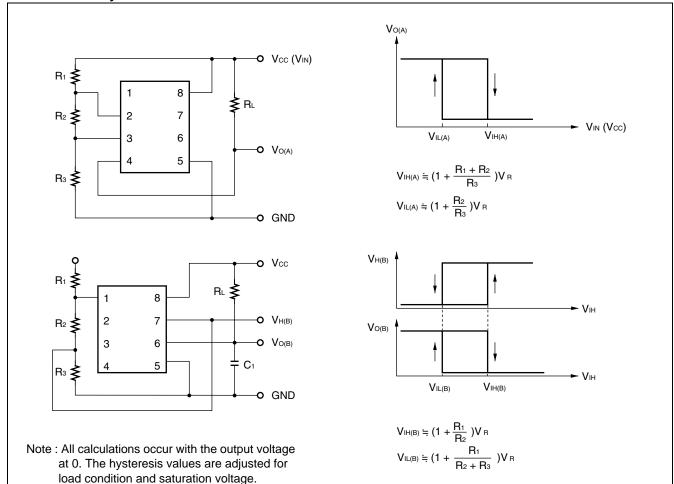


Threshold Voltage vs.
Operating Ambient Temperature

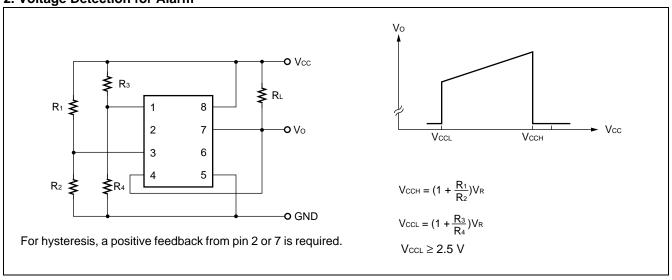


■ APPLICATION EXAMPLES

1. Addition of Hysteresis



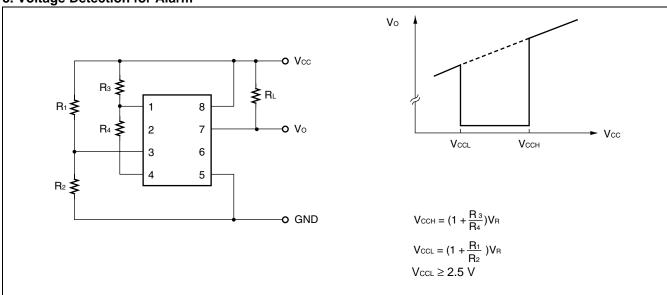
2. Voltage Detection for Alarm



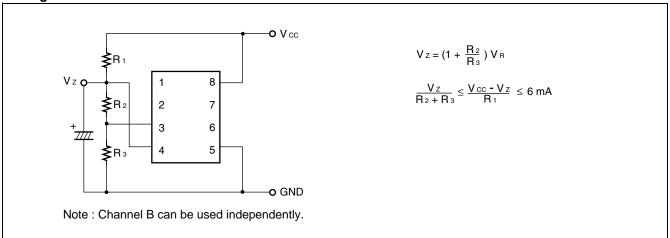
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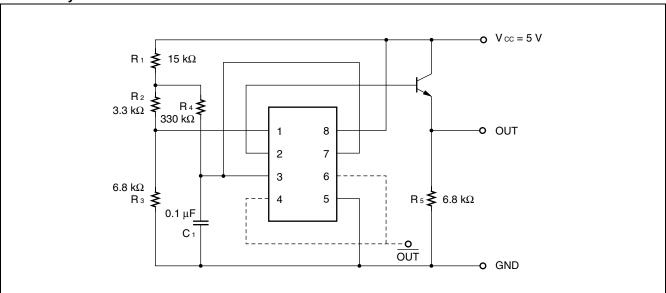
3. Voltage Detection for Alarm



4. Programmable Zener



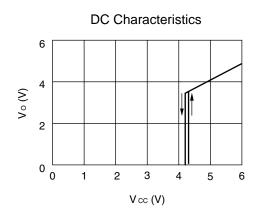
5. Recovery Reset Circuit



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■ TYPICAL CHARACTERISTICS



 Voltage Threshold Levels (VccL and VccH) and Hysteresis Width can be changed by the resistors (R1 through R4).

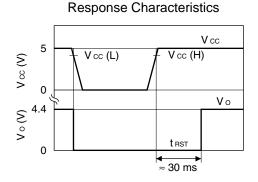
$$VCCL = \frac{R1 + R2 + R3}{R3} VTH$$

$$VCCH = VCCL + \frac{R1 (R2 + R3)}{R3 R4} VTH$$

• Power-On Reset Time is provided by the following approximate equation:

trst = -C1 R4 • In
$$\left\{1 - \frac{V_{TH}}{V_{CC}} \left(1 + \frac{R_1}{R_2 + R_3}\right)\right\}$$

- The recommended value of hFE of the external transistor is from 50 to 200.
- In the case of an instant power fail, the remaining charge in C1 effects trst.
- If necessary, the reversed output is provided on HYS terminal



■ NOTES ON USE

- Take account of common impedance when designing the earth line on a printed wiring board.
- Take measures against static electricity.
 - For semiconductors, use antistatic or conductive containers.
 - When storing or carrying a printed circuit board after chip mounting, put it in a conductive bag or container.
 - The work table, tools and measuring instruments must be grounded.
 - The worker must put on a grounding device containing 250 k Ω to 1 M Ω resistors in series.
- Do not apply a negative voltage
 - Applying a negative voltage of –0.3 V or less to an LSI may generate a parasitic transistor, resulting in malfunction.

ORDERING INFORMATION

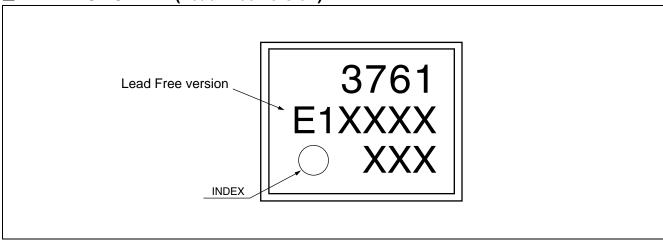
Part number	Package	Remarks
MB3761PF-□□□	8-pin plastic SOP (FPT-8P-M01)	Conventional version
MB3761PF-□□□E1	8-pin plastic SOP (FPT-8P-M01)	Lead Free version

■ RoHS Compliance Information of Lead (Pb) Free version

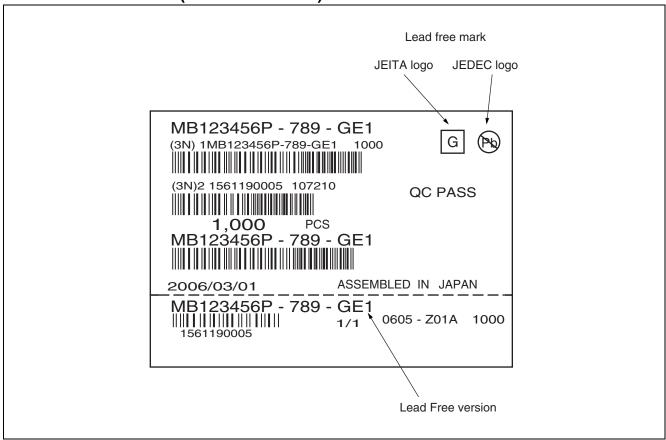
The LSI products of Fujitsu with "E1" are compliant with RoHS Directive, and has observed the standard of lead, cadmium, mercury, Hexavalent chromium, polybrominated biphenyls (PBB), and polybrominated diphenyl ethers (PBDE).

The product that conforms to this standard is added "E1" at the end of the part number.

■ MARKING FORMAT (Lead Free version)



■ LABELING SAMPLE (Lead free version)

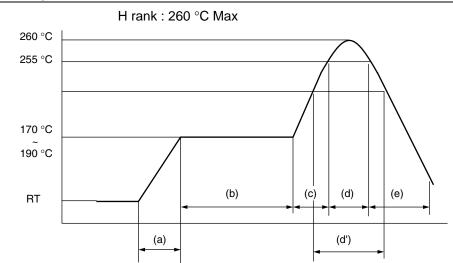


■ MB3761PF-□□□E1 RECOMMENDED CONDITIONS OF MOISTURE SENSITIVITY LEVEL

Item	Condition		
Mounting Method	IR (infrared reflow) , Manual soldering (partial heating method)		
Mounting times	2 times		
Storage period	Before opening	Please use it within two years after Manufacture.	
	From opening to the 2nd reflow	Less than 8 days	
	When the storage period after opening was exceeded	Please processes within 8 days after baking (125 °C, 24H)	
Storage conditions	5 °C to 30 °C, 70%RH or less (the lowest possible humidity)		

[Temperature Profile for FJ Standard IR Reflow]

(1) IR (infrared reflow)



(a) Temperature Increase gradient : Average 1 °C/s to 4 °C/s

(b) Preliminary heating : Temperature 170 °C to 190 °C, 60s to 180s

(c) Temperature Increase gradient : Average 1 °C/s to 4 °C/s

(d) Actual heating : Temperature 260 °C Max; 255 °C or more, 10s or less

(d') : Temperature 230 °C or more, 40s or less

or

Temperature 225 °C or more, 60s or less

or

Temperature 220 $^{\circ}\text{C}$ or more, 80s or less

(e) Cooling : Natural cooling or forced cooling

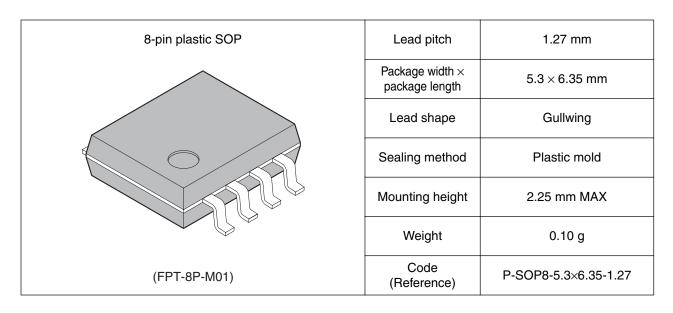
Note: Temperature: the top of the package body

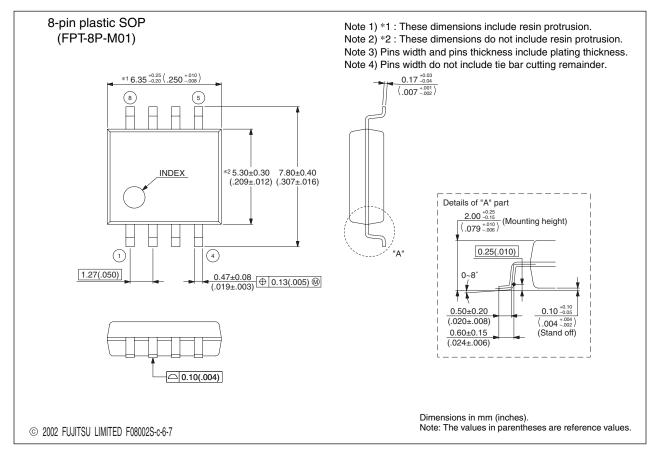
(2) Manual soldering (partial heating method)

Conditions : Temperature 400 °C Max

Times : 5 s max/pin

■ PACKAGE DIMENSION





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